TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSV)

2SK3399

Switching Regulator Applications

- Low drain-source ON resistance: $R_{DS (ON)} = 0.54 \Omega (typ.)$
- High forward transfer admittance: |Yfs| = 5.2 S (typ.)
- Low leakage current: I_{DSS} = 100 μA (max) (V_{DS} = 600 V)
- Enhancement mode: V_{th} = 3.0 to 5.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			V_{DSS}	600	(///)
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)			V_{DGR}	600	A
Gate-source voltage			V_{GSS}	±30	y
Drain current	DC	(Note 1)	ΙD	10	⇒ _A
	Pulse	(Note 1)	I _{DP}	40	, A
Drain power dissipation (Tc = 25°C)			P_{D}	100	W
Single pulse avalanche energy (Note 2)			EAS	363	mJ mJ
Avalanche current			IAR	10	A
Repetitive avalanche energy (Note 3)			EAR	10	mJ
Channel temperature			(T _{ch} \	150) °C
Storage temperature range			T _{stg}	–55 to 150	7,¢

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	1.25	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	83.3	°C/W

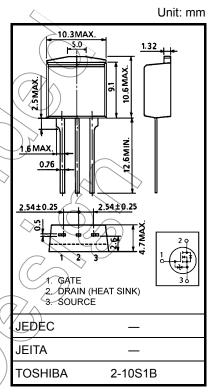
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD} = 90 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$ (initial), L = 6.36 mH, $R_G = 25 \Omega$, $I_{AR} = 10 \text{ A}$

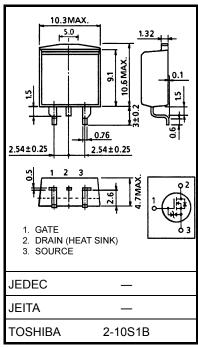
Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.



Weight: 1.5 g (typ.)



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Electrical Characteristics (Ta = 25°C)

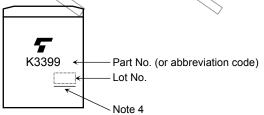
Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage cur	rent	I _{GSS}	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА	
Gate-source brea	kdown voltage	V _(BR) GSS	$I_G = \pm 10 \ \mu A, \ V_{DS} = 0 \ V$	±30	_		V	
Drain cut-off current		I _{DSS}	V _{DS} = 600 V, V _{GS} = 0 V		_	100	μΑ	
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10$ mA, $V_{GS} = 0$ V	600	_	_	V	
Gate threshold voltage		V _{th}	V _{DS} = 10 V, I _D = 1 mA	3.0) /~	5.0	V	
Drain-source ON resistance		R _{DS (ON)}	V _{GS} = 10 V, I _D = 5 A	<u> </u>	0.54	0.75	Ω	
Forward transfer admittance		Y _{fs}	V _{DS} = 10 V, I _D = 5 A	2.0	5.2	_	S	
Input capacitance)	C _{iss}		\	1750			
Reverse transfer	capacitance	C _{rss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	_	11	_	pF	
Output capacitance		Coss		_	170	_		
Switching time	Rise time	t _r	V _{GS} ID=5 A V _{OUT}	- (15	×		
	Turn-on time	t _{on}	0 V S P 40 O		40	_		
	Fall time	t _f	V _{IN} ; t _t , t _f < 5 ns V _{DD} ~ 200 V		8		ns	
	Turn-off time	t _{off}	Duty $\leq 1\%$, $t_W = 10 \mu s$) —	35			
Total gate charge (Gate-source plus gate-drain)		Qg			35			
Gate-source charge		Qgs	$V_{DD} \simeq 400 \text{ V}, V_{GS} = 10 \text{ V}, D = 10 \text{ A}$	_	15	_	nC	
Gate-drain ("Miller") charge		Qgd		_	20	_		

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	_			10	Α
Pulse drain reverse current (Note 1)	IDRP				40	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 10 A, V _{GS} = 0 V			-1.7	V
Reverse recovery time	\rightarrow t _{rr}	I _{DR} = 10 A, V _{GS} = 0 V,		1300		ns
Reverse recovery charge	Q_{rr}	dI _{DR} /dt = 100 A/μs	_	16	_	μС

2

Marking

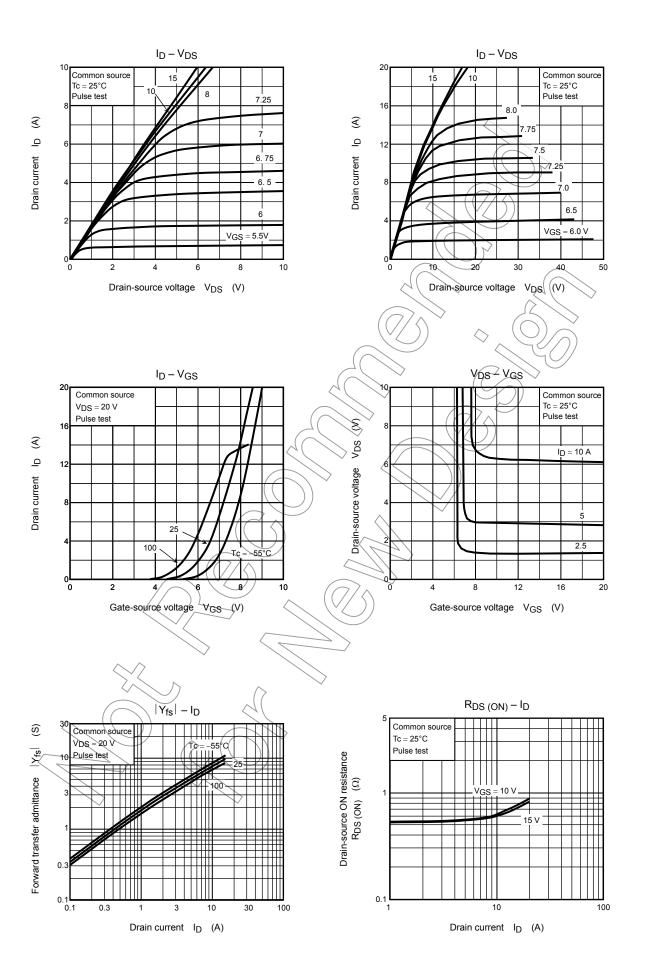


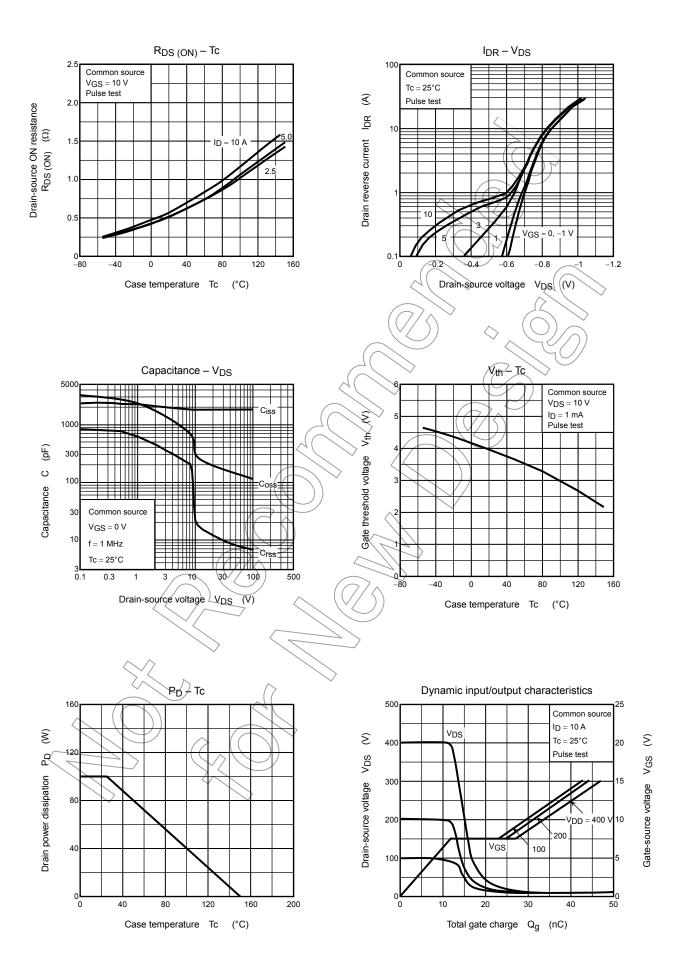
Note 4: A line under a Lot No. identifies the indication of product Labels.

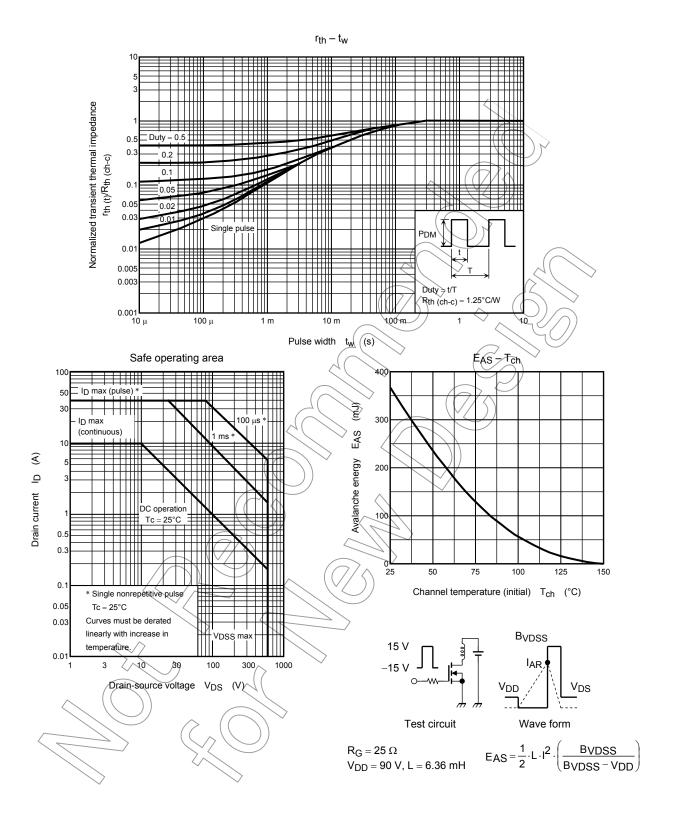
Not underlined: [[Pb]]/INCLUDES > MCV

 $\label{thm:compatible} \begin{tabular}{ll} Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]] \end{tabular}$

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.







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